

40V N-Channel Enhancement Mode MOSFET

Voltage

Current 79 A

Features

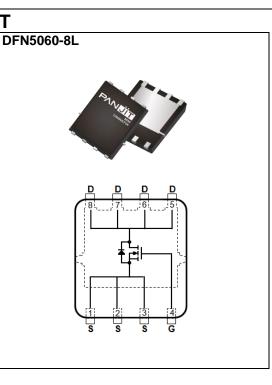
• $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A < 5.9m\Omega$

40 V

- $R_{DS(ON)}$, $V_{GS}@7V$, $I_D@20A < 7.3m\Omega$
- Excellent FOM
- Standard Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.08 grams



Maximum Ratings and Thermal Characteristics (T_A=25^oC unless otherwise noted)

PARAMETE	R	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40	V	
Gate-Source Voltage		V _{GS}	±20	V	
Constitution Duration Occurrence (Note 3)	T _c =25°C		79		
Continuous Drain Current ^(Note 3)	Tc=100°C	I _D	55	А	
Pulsed Drain Current ^(Note 1)	T _c =25°C	I _{DM}	316		
Power Dissipation	T _c =25°C	D _	65	14/	
	Tc=100°C	PD	33	W	
Continuous Drain Current ^(Note 4)	T _A =25°C		17.7		
	T _A =70 [°] C	ID	14.8	— A	
Power Dissipation	T _A =25 [°] C	Da	3.3	W	
	T _A =70°C	PD	2.3	VV	
Single Pulse Avalanche Energy ^(Note 5)		Eas	100	mJ	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~175	°C	
Thermal Resistance ^(Note 4)	Junction to Case	R _{θJC}	2.3	°C/W	
	Junction to Ambient	R _{0JA}	45		



Electrical Characteristics (T_A=25°C unless otherwise noted)

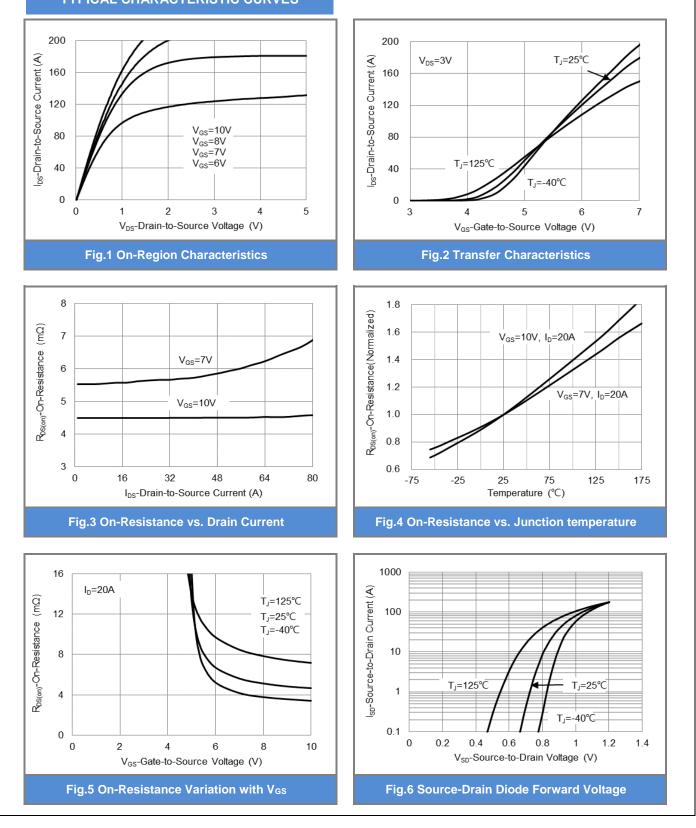
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =50uA	2	2.8	3.5	V
	RDS(on)	V _{GS} =10V, I _D =20A	-	4.7	5.9	mΩ
Drain-Source On-State Resistance		V _{GS} =7V, I _D =20A	-	5.6	7.3	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =40V, V_{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Qg		-	23	-	nC
Gate-Source Charge	Qgs	V _{DS} =32V, I _D =20A, V _{GS} =10V	-	5	-	
Gate-Drain Charge	Q_gd		-	6	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1MHz	-	1283	-	pF
Output Capacitance	Coss		-	252	-	
Reverse Transfer Capacitance	Crss		-	46	-	
Gate resistance	Rg	f=1MHz	-	0.8	-	Ω
Turn-On Delay Time	td _(on)	V _{DS} =32V, I _D =20A, V _{GS} =10V, R _G =3Ω (Note 2)	-	17	-	ns
Turn-On Rise Time	tr		-	79	-	
Turn-Off Delay Time	td(off)		-	37	-	
Turn-Off Fall Time	tf		-	23	-	
Drain-Source Diode	•					
Diode Forward Current	I _S	Tc=25°C	-	-	79	A
Pulsed Diode Forward Current	I _{SM}		-	-	316	
Diode Forward Voltage	V _{SD}	Is=20A, V _{GS} =0V	-	0.85	1.3	V
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =20A	-	43	-	ns
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	34	-	nC

NOTES :

- 1. Pulse width100us, Duty cycle<2%.</td>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\theta JC}=2.3^{\circ}C/W$.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS}=20A, V_{DD}=30V, V_{GS}=10V, Starting T_J=25^{\circ}C.
- 6. Guaranteed by design, not subject to production testing.

January 30,2023

PJQ5546V-AU-REV.00



TYPICAL CHARACTERISTIC CURVES

PANJ SEM

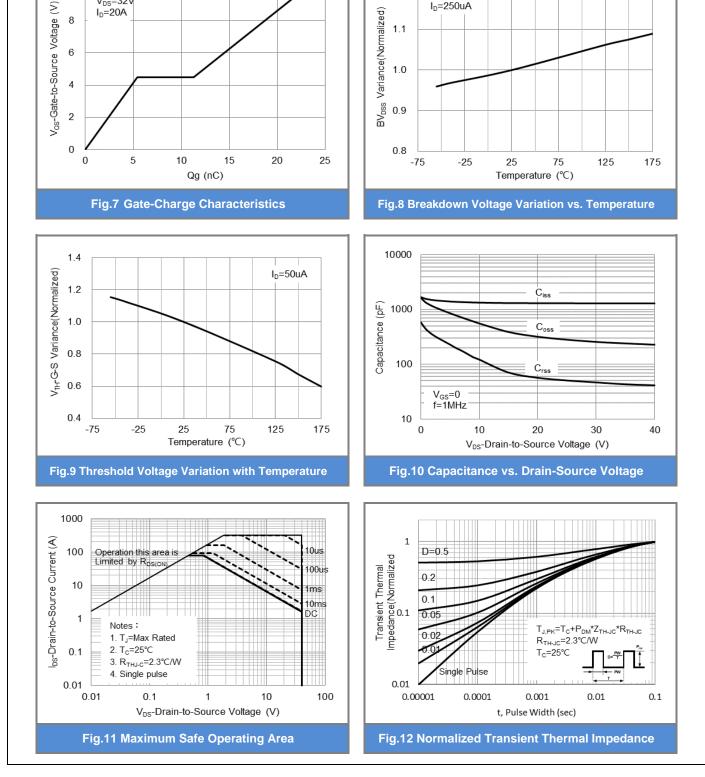


PJQ5546V-AU

January 30,2023

PJQ5546V-AU-REV.00





1.2

1.1

1.0

In=250uA

TYPICAL CHARACTERISTIC CURVES



10

8

6

4

PJQ5546V-AU

V_{DS}=32V

I_D=20A

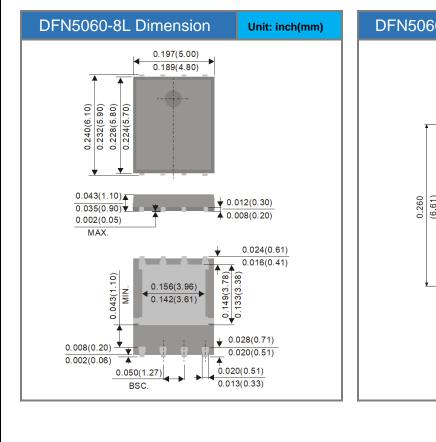


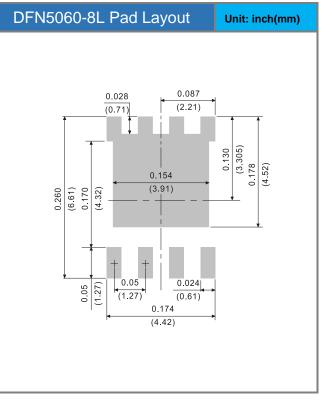


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ5546V-AU_R2_002A1	DFN5060-8L	3K pcs / 13" reel	Q5546V	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout







Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.